

1

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A

B

C

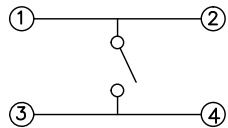
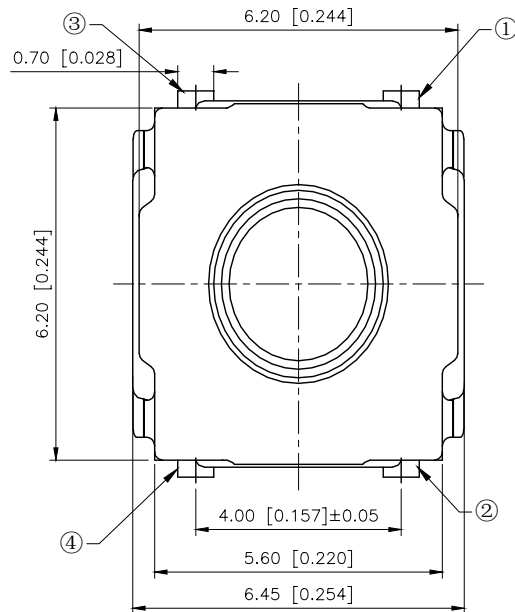
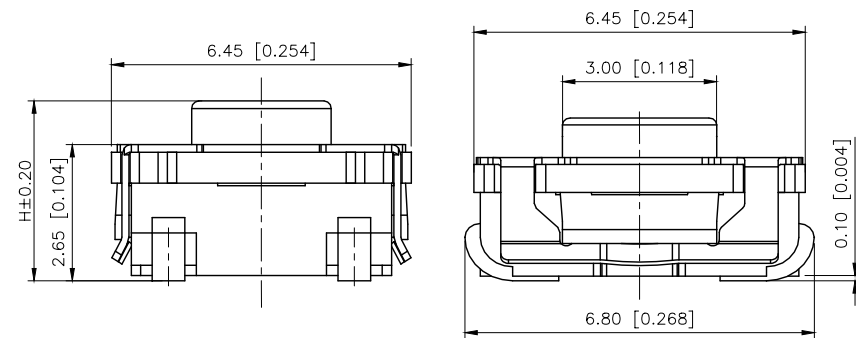
D

A

B

C

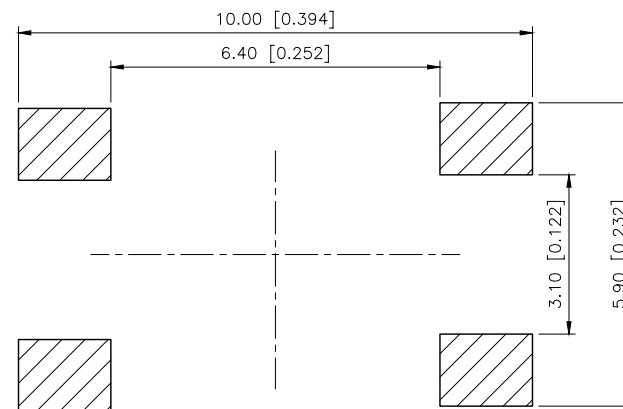
D



Circuit Diagram

REVISIONS					
REV.	ECN NO.	LOCATION	DESCRIPTION	DATE	DESIGN
A0	N/A		INITIAL RELEASE	/	/
A1	N/A		图面升级整理图面	2025.06.05	阿树

SPECIFICATION
Contact Rating: 50mA,12V DC
Contact Resistance: 100mΩ max
Insulation Resistance: 100MΩ min.500V DC
Dielectric Strength: 250V AC/1minute
Travel: 0.25mm
Operating Temp: -30℃~+85℃
Storage Temp: -30℃~+85℃



PAPT NO	TS-1159UB-B-D-BL
Operating Force	A:100gf B:160gf C:260gf D:320gf E:400gf
Height	H:A:3.5 B:4.3 C:4.9 D:5.2
Color	W:white BL:blue

⑤	Terminal	4	Brass (0.30t)	Plating silvering	
④	Contact	1	F.ag/SUS	Natural	
③	Base	1	PA46		
②	Cover	1	SPSS	Plating Nickel	
①	Keystake	1	Silica gel		
ITEM	PAPT	NAMF	QTY	MATERIAL	FINISHING

AuGLAR	±5°
X.	±0.40
X.x	±0.30
X.xx	±0.20
X.xxx	±0.15
UNSPECIFIED TOLERANCE	



DESIGN	阿树	VIEW:		MODEL TYPE:	TACT SWITCH
CHECKED		UNIT:	mm/in	PART NO.:	TS-1159UB-B-D-BL
APPROVED		SIZE:	A4	DWG NO.:	TS-1159UB-B-D-BL
		SCALE	N/A	PAGE	1/1
		REVISION			A1

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